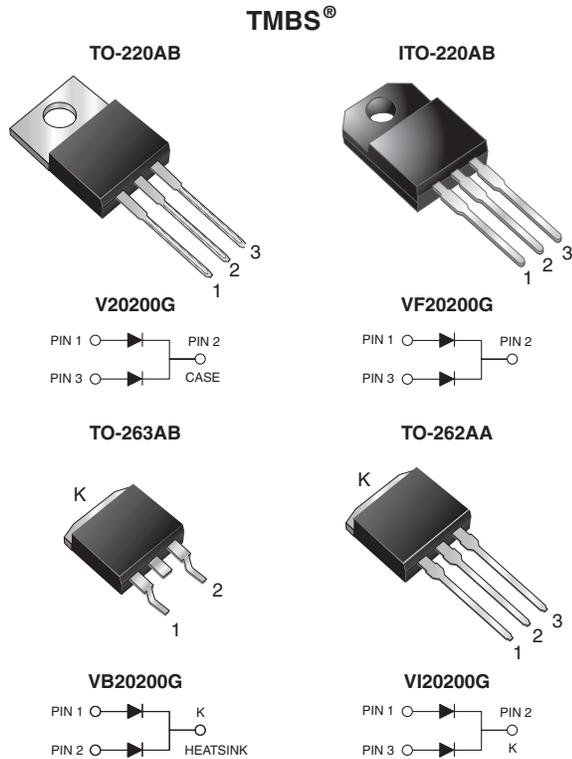


Dual High Voltage Trench MOS Barrier Schottky Rectifier

 Ultra Low $V_F = 0.62 \text{ V}$ at $I_F = 5 \text{ A}$


FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- High efficiency operation
- Low thermal resistance
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AB, ITO-220AB and TO-262AA package)
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912


RoHS
COMPLIANT

TYPICAL APPLICATIONS

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, DC/DC converters and reverse battery protection.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, TO-263AB and TO-262AA

Molding compound meets UL 94 V-0 flammability rating
Base P/N-E3 - RoHS compliant, commercial grade

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs max.

PRIMARY CHARACTERISTICS

| | |
|-------------------------------|---|
| $I_{F(AV)}$ | 2 x 10 A |
| V_{RRM} | 200 V |
| I_{FSM} | 110 A |
| V_F at $I_F = 10 \text{ A}$ | 0.71 V |
| T_J max. | 150 °C |
| Package | TO-220AB, ITO-220AB, TO-263AB, TO-262AA |
| Diode variations | Common cathode |

MAXIMUM RATINGS ($T_A = 25 \text{ °C}$ unless otherwise noted)

| PARAMETER | SYMBOL | V20200G | VF20200G | VB20200G | VI20200G | UNIT |
|---|----------------|---------------|----------|----------|----------|------------------|
| Max. repetitive peak reverse voltage | V_{RRM} | 200 | | | | V |
| Max. average forward rectified current (fig. 1) | $I_{F(AV)}$ | per device | | 20 | | A |
| | | per diode | | 10 | | |
| Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode | I_{FSM} | 110 | | | | A |
| Non-repetitive avalanche energy at $T_J = 25 \text{ °C}$, $L = 60 \text{ mH}$ per diode | E_{AS} | 60 | | | | mJ |
| Peak repetitive reverse current at $t_p = 2 \text{ } \mu\text{s}$, 1 kHz, $T_J = 38 \text{ °C} \pm 2 \text{ °C}$ per diode | I_{RRM} | 0.5 | | | | A |
| Voltage rate of change (rated V_R) | dV/dt | 10 000 | | | | V/ μs |
| Isolation voltage (ITO-220AB only) from terminal to heatsink $t = 1 \text{ min}$ | V_{AC} | 1500 | | | | V |
| Operating junction and storage temperature range | T_J, T_{STG} | - 40 to + 150 | | | | °C |



ELECTRICAL CHARACTERISTICS ($T_A = 25\text{ }^\circ\text{C}$ unless otherwise noted)

| PARAMETER | TEST CONDITIONS | | SYMBOL | TYP. | MAX. | UNIT |
|--|-----------------------|-----------------------------------|----------|------------|------|---------------|
| Breakdown voltage | $I_R = 1.0\text{ mA}$ | $T_J = 25\text{ }^\circ\text{C}$ | V_{BR} | 200 (min.) | - | V |
| Instantaneous forward voltage per diode ⁽¹⁾ | $I_F = 5\text{ A}$ | $T_J = 25\text{ }^\circ\text{C}$ | V_F | 0.86 | - | V |
| | $I_F = 10\text{ A}$ | | | 1.23 | 1.70 | |
| | $I_F = 5\text{ A}$ | $T_J = 125\text{ }^\circ\text{C}$ | | 0.62 | - | |
| | $I_F = 10\text{ A}$ | | | 0.71 | 0.80 | |
| Reverse current per diode ⁽²⁾ | $V_R = 180\text{ V}$ | $T_J = 25\text{ }^\circ\text{C}$ | I_R | 1.9 | - | μA |
| | | $T_J = 125\text{ }^\circ\text{C}$ | | 1.6 | - | mA |
| | $V_R = 200\text{ V}$ | $T_J = 25\text{ }^\circ\text{C}$ | | - | 150 | μA |
| | | $T_J = 125\text{ }^\circ\text{C}$ | | 2.5 | 15 | mA |

Notes

- (1) Pulse test: 300 μs pulse width, 1 % duty cycle
- (2) Pulse test: Pulse width $\leq 40\text{ ms}$

THERMAL CHARACTERISTICS ($T_A = 25\text{ }^\circ\text{C}$ unless otherwise noted)

| PARAMETER | SYMBOL | V20200G | VF20200G | VB20200G | VI20200G | UNIT |
|--------------------------------------|-----------------|---------|----------|----------|----------|--------------------|
| Typical thermal resistance per diode | $R_{\theta JC}$ | 3.2 | 5.5 | 3.2 | 3.2 | $^\circ\text{C/W}$ |

ORDERING INFORMATION (EXAMPLE)

| PACKAGE | PREFERRED P/N | UNIT WEIGHT (g) | PACKAGE CODE | BASE QUANTITY | DELIVERY MODE |
|-----------|----------------|-----------------|--------------|---------------|---------------|
| TO-220AB | V20200G-E3/4W | 1.88 | 4W | 50/tube | Tube |
| ITO-220AB | VF20200G-E3/4W | 1.75 | 4W | 50/tube | Tube |
| TO-263AB | VB20200G-E3/4W | 1.39 | 4W | 50/tube | Tube |
| TO-263AB | VB20200G-E3/8W | 1.39 | 8W | 800/reel | Tape and reel |
| TO-262AA | VI20200G-E3/4W | 1.45 | 4W | 50/tube | Tube |

RATINGS AND CHARACTERISTICS CURVES

($T_A = 25\text{ }^\circ\text{C}$ unless otherwise noted)

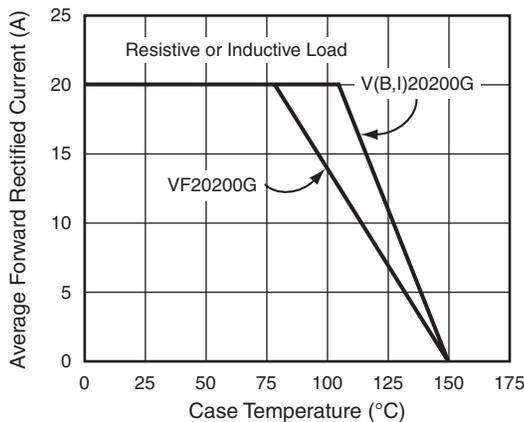


Fig. 1 - Maximum Forward Current Derating Curve

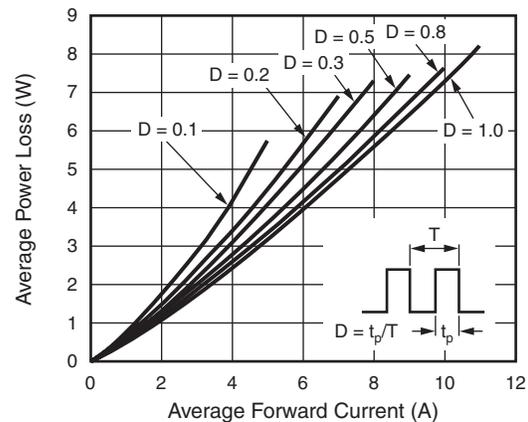


Fig. 2 - Forward Power Loss Characteristics Per Diode

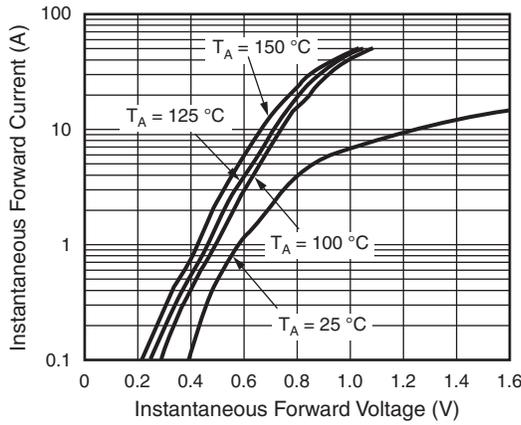


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

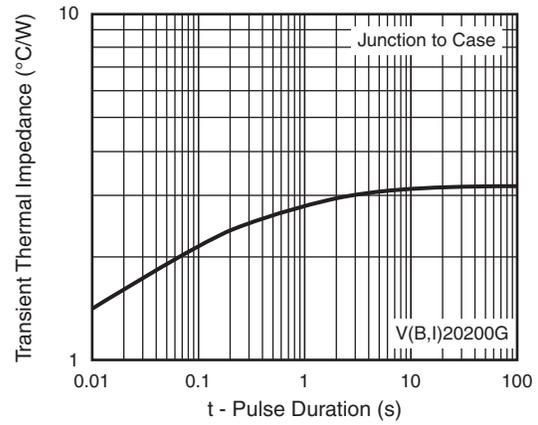


Fig. 6 - Typical Transient Thermal Impedance Per Diode

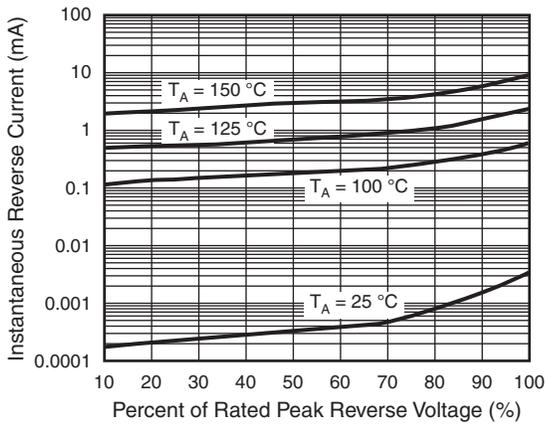


Fig. 4 - Typical Reverse Characteristics Per Diode

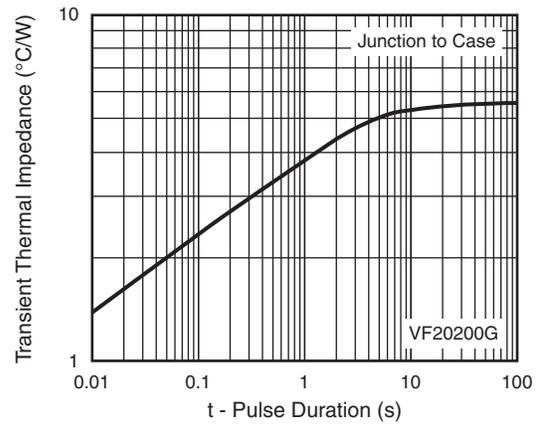


Fig. 7 - Typical Transient Thermal Impedance Per Diode

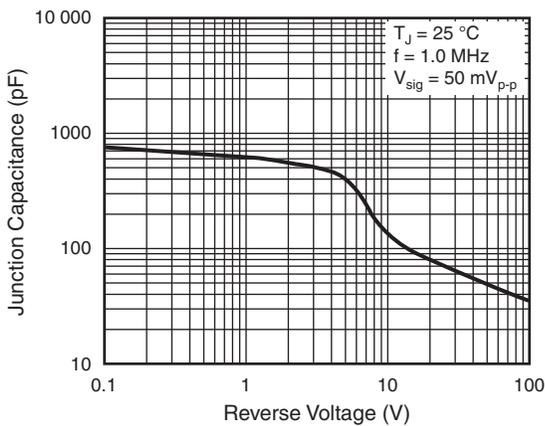
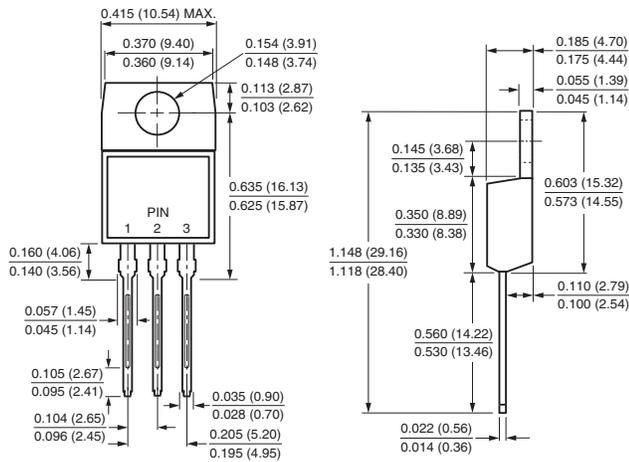


Fig. 5 - Typical Junction Capacitance Per Diode

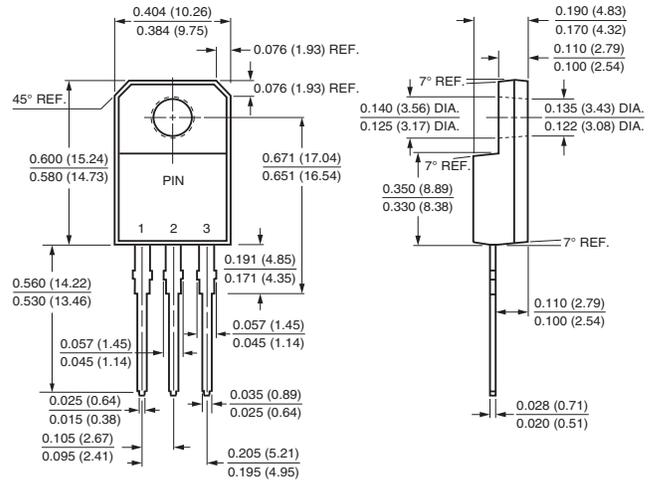


PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

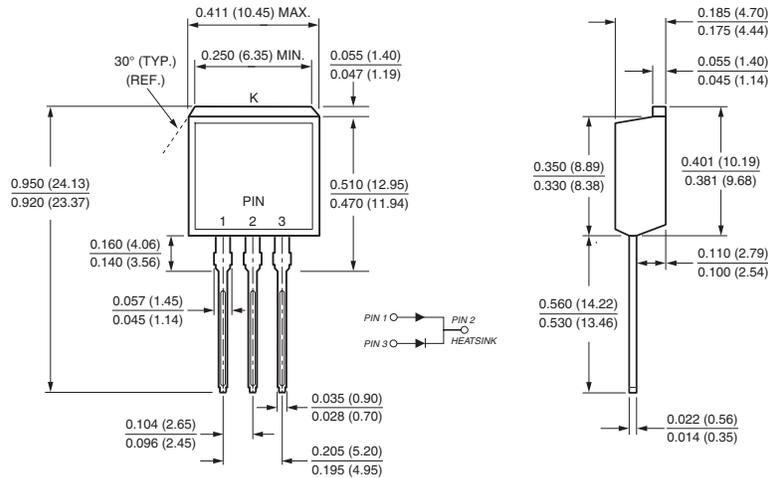
TO-220AB



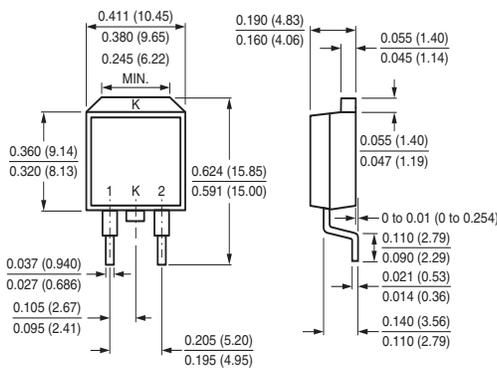
ITO-220AB



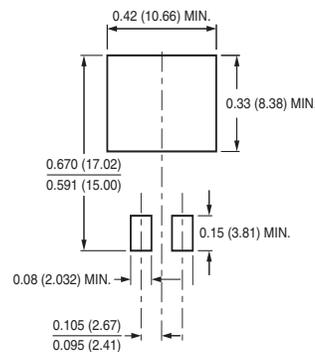
TO-262AA



TO-263AB



Mounting Pad Layout





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